Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:	
/letal	
Overall Length:	
0.210 inches	
Ferminal Length:	
0.500 inches	
Overall Diameter:	
0.230 inches	
nternal Configuration:	
lunction contact	
loint Electronic Device Engineering Council/jedec/case Outline Design	ation:
Го-18	
Nounting Method:	
Ferminal	
Ferminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
/oltage Rating In Volts Per Characteristic:	
.0 on-state voltage, dc	
Current Rating Per Characteristic:	
50.00 milliamperes forward current, total rms nanoamperes	
Naximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius case	
Special Features:	
nternal junction configuration arrangement pnpn	
Ferminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Jnit Of Measure:	
-	
Demilitarization:	
No	
Filg:	
\110a0	